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Dual 2-Bit Dual-Supply Non-Inverting Level Translator

The NLSV22T244 is a dual 2-bit configurable dual-supply bus buffer level translator. The input ports A and the output ports B are designed to track two different power supply rails V_{CCA} and V_{CCB} . Both supply rails are configurable from 1.6 V to 3.6 V allowing universal low-voltage translations from the input port A to the output B port.

Features

- Wide V_{CCA} and V_{CCB} Operating Range: 1.6 V to 3.6 V
- High-Speed w/ Balanced Propagation Delay
- Inputs and Outputs have OVT Protection to 5.5 V
- Non-preferential V_{CCA} and V_{CCB} Sequencing
- Outputs at 3-State until Active V_{CC} is reached
- Power-Off Protection
- Ultra-Small packaging: 1.7mm x 2.0 mm UQFN-12
- This is a Pb-Free Device

Typical Applications

• Mobile Phones, PDAs, Other Portable Devices

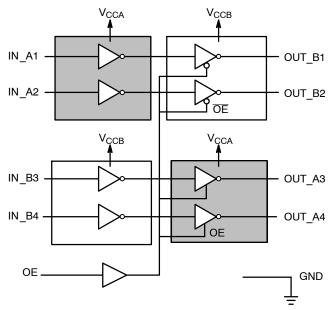


Figure 1. Logic Diagram



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DIAGRAM WEM

MARKING

UQFN12 MU SUFFIX CASE 523AE

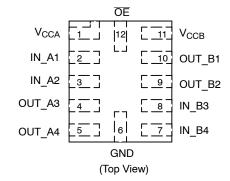
WE = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

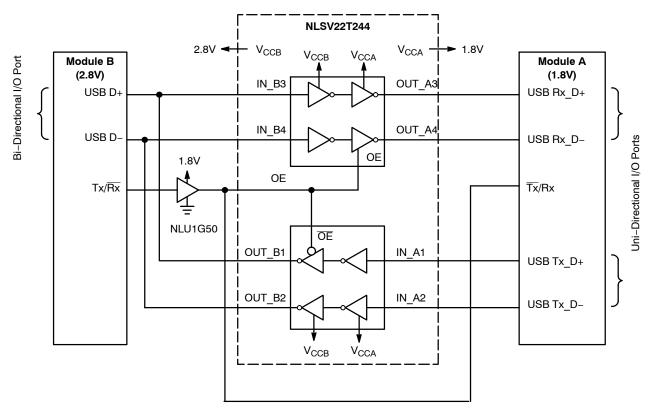
PIN ASSIGNMENT



ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-----------------|---------------------|-----------------------|
| NLSV22T244MUTAG | UQFN12 (Pb-Free) | 3000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.



 $\mathsf{OE} = \mathsf{High}, \, \mathsf{Module} \, \mathsf{B} \, \mathsf{Transmits}, \, \mathsf{Module} \, \mathsf{A} \, \mathsf{Receives} = \mathsf{B} \to \mathsf{A}$

OE = Low, Module A Transmits, Module B Receives = $\mathbf{A} \to \mathbf{B}$

Figure 2. Typical Application Bi-Directional to Uni-Directional Logic Level Translator

PIN ASSIGNMENT

| Pin | Function |
|--------------------------------|-------------------|
| V _{CCA} | A DC Power Supply |
| V _{CCB} | B DC Power Supply |
| GND | Ground |
| IN_A1, IN_A2, IN_B3, IN_B4 | Inputs |
| OUT_B1, OUT_B2, OUT_A3, OUT_A4 | Outputs |
| OE | Output Enable |

| In | puts | Out | outs | |
|----|----------------|-----------------|-------------------|------------------|
| OE | IN_A1 IN_A2 | IN_B3, IN_B4 | OUT_B1, OUT_B2 | OUT_A3 OUT_A4 |
| Н | Х | L | 3-State | L |
| | L | Н | | Н |
| L | L | Х | L | 3-State |
| | Н | | Н | |

MAXIMUM RATINGS

| Symbol | R | ating | Value | Condition | Unit |
|-------------------------------------|-------------------------------------|---------------------------------|--------------|---|------|
| V _{CCA} , V _{CCB} | DC Supply Voltage | | -0.5 to +5.5 | | V |
| VI | DC Input Voltage | IN_X _n | -0.5 to +5.5 | | V |
| V _C | Control Input | OE | -0.5 to +5.5 | | V |
| Vo | DC Output Voltage | (Power Down) OUT_X _n | -0.5 to +5.5 | V _{CCA} = V _{CCB} = 0 | V |
| | (Active Mode) OUT_X _n | | -0.5 to +5.5 | | |
| | (Tri-State Mode) OUT_X _n | | -0.5 to +5.5 | | |
| I _{IK} | DC Input Diode Currer | nt | -20 | V _I < GND | mA |
| l _{OK} | DC Output Diode Current | | -50 | V _O < GND | mA |
| I _O | DC Output Source/Sink Current | | ±50 | | mA |
| I _{CCA} , I _{CCB} | DC Supply Current Per Supply Pin | | ±100 | | mA |
| I _{GND} | DC Ground Current per Ground Pin | | ±100 | | mA |
| T _{STG} | Storage Temperature | | -65 to +150 | | °C |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Unit |
|-------------------------------------|---|-----|-----|------|
| V _{CCA} , V _{CCB} | Positive DC Supply Voltage | 1.6 | 3.6 | V |
| VI | Bus Input Voltage | GND | 3.6 | V |
| V _C | Control Input OE | GND | 3.6 | V |
| V _{IO} | Bus Output Voltage (Power Down Mode) OUT_X _n | GND | 3.6 | V |
| | (Active Mode) OUT_X _n | GND | 3.6 | V |
| | (Tri-State Mode) OUT_X _n | GND | 3.6 | V |
| T _A | Operating Temperature Range | -40 | +85 | °C |
| Δt / ΔV | Input Transition Rise or Rate V _I , from 30% to 70% of V _{CC} ; V _{CC} = 3.3 V \pm 0.3 V | 0 | 10 | nS |

DC ELECTRICAL CHARACTERISTICS

| | | | | | -40°C t | o +85°C | |
|-------------------------------------|---|--|----------------------|----------------------|-------------------------|-------------------------|------|
| Symbol | Parameter | Test Conditions | V _{CCA} (V) | V _{CCB} (V) | Min | Max | Unit |
| V _{IH} | Input HIGH Voltage | | 2.7 – 3.6 | 1.6 – 3.6 | 2.0 | _ | V |
| | | | 2.3 – 2.7 | 1 | 1.6 | - | |
| | | | 1.4 – 2.3 | 1 | 0.65 * V _{CCA} | _ | |
| V_{IL} | Input LOW Voltage | | 2.7 – 3.6 | 1.6 – 3.6 | - | 0.8 | V |
| | | | 2.3 – 2.7 | 1 | - | 0.7 | |
| | | | 1.6 – 2.3 | 1 | _ | 0.35 * V _{CCA} | |
| V _{OH} | Output HIGH Voltage | $I_{OH} = -100 \mu A; V_I = V_{IH}$ | 1.6 – 3.6 | 1.6 – 3.6 | V _{CCB} - 0.2 | _ | V |
| | | $I_{OH} = -6 \text{ mA}; V_I = V_{IH}$ | 1.6 | 1.6 | 1.25 | _ | |
| | | | 2.3 | 2.3 | 2.0 | _ | |
| | | $I_{OH} = -12 \text{ mA}; V_I = V_{IH}$ | 2.3 | 2.3 | 1.8 | _ | |
| | | | 2.7 | 2.7 | 2.2 | _ | |
| | | $I_{OH} = -18 \text{ mA}; V_I = V_{IH}$ | 2.3 | 2.3 | 1.7 | - | |
| | | | 3.0 | 3.0 | 2.4 | _ | |
| | | $I_{OH} = -24 \text{ mA}; V_I = V_{IH}$ | 3.0 | 3.0 | 2.2 | _ | |
| V _{OL} | Output LOW Voltage | $I_{OL} = 100 \mu A; V_I = V_{IL}$ | 1.6 – 3.6 | 1.6 – 3.6 | - | 0.2 | V |
| | | $I_{OL} = 6 \text{ mA}; V_I = V_{IL}$ | 1.6 | 1.6 | - | 0.3 | |
| | | I_{OL} = 12 mA; V_I = V_{IL} | 2.3 | 2.3 | - | 0.4 | |
| | | | 2.7 | 2.7 | - | 0.4 | |
| | | I_{OL} = 18 mA; $V_I = V_{IL}$ | 2.3 | 2.3 | - | 0.6 | |
| | | | 3.0 | 3.0 | - | 0.5 | |
| | | I_{OL} = 24 mA; V_I = V_{IL} | 3.0 | 3.0 | - | 0.6 | |
| I _I | Input Leakage Current | V _I = V _{CCA} or GND | 1.6 – 3.6 | 1.6 – 3.6 | -1.0 | +1.0 | μΑ |
| I _{OZ} | I/O Tri-State Output Leakage Current | $T_A = 25^{\circ}C$, OE = GND | 1.6 – 3.6 | 1.6 – 3.6 | - | 2.0 | μΑ |
| I _{CCA} | Quiescent Supply Current | $V_I = V_{CCA}$ or GND; $I_O = 0$ | 1.6 – 3.6 | 1.6 – 3.6 | - | 2.0 | μΑ |
| I _{CCB} | Quiescent Supply Current | $V_I = V_{CCA}$ or GND; $I_O = 0$ | 1.6 – 3.6 | 1.6 – 3.6 | _ | 2.0 | μΑ |
| I _{CCA} + I _{CCB} | Quiescent Supply Current | $V_I = V_{CCA}$ or GND; $I_O = 0$ | 1.6 – 3.6 | 1.6 – 3.6 | - | 4.0 | μΑ |

TOTAL STATIC POWER CONSUMPTION (I_{CCA} + I_{CCB})

| | | (OOA O | OD, | | | | |
|----------------------|-----|----------------------|-------|----------|-----|-------|------|
| | | | −40°C | to +85°C | | | |
| | | V _{CCB} (V) | | | | | |
| | 3 | 3.6 2.8 1.6 | | | 1.6 | | |
| V _{CCA} (V) | Min | Max | Min | Max | Min | Max | Unit |
| 3.6 | | 2 | | 2 | | 2 | μΑ |
| 2.8 | | < 1 | | < 1 | | < 0.5 | μΑ |
| 1.6 | | < 1 | | < 1 | | < 0.5 | μΑ |

NOTE: Connect ground before applying supply voltage V_{CCA} or V_{CCB} . This device is designed with the feature that the power-up sequence of V_{CCA} and V_{CCB} will not damage the IC.

AC ELECTRICAL CHARACTERISTICS

| | | | | | -40°C 1 | to +85°C | | | |
|---------------------|--|----------------------|-----|------|-----------------|------------------|-----|------|------|
| | | | | | V _{CC} | _B (V) | | | |
| | | | 3 | 3.6 | 2 | 2.8 | 1 | .6 | |
| Symbol | Parameter | V _{CCA} (V) | Min | Max | Min | Max | Min | Max | Unit |
| t _{PLH} , | Propagation Delay, | 3.6 | | 3.4 | | 3.6 | | 3.8 | nS |
| t _{PHL} | A _n to B _n | 2.8 | | 3.6 | | 3.8 | | 4.0 | |
| | | 1.6 | | 3.9 | | 4.0 | | 4.5 | |
| t _{PZH} , | Output Enable, OE to OUT_X _n | 3.6 | | 5.8 | | 6.0 | | 6.2 | nS |
| t_{PZL} | | 2.8 | | 6.0 | | 6.2 | | 6.4 | |
| | | 1.6 | | 8.2 | | 8.4 | | 8.6 | |
| t _{PHZ} , | Output Disable, | 3.6 | | 5.8 | | 6.0 | | 6.2 | nS |
| t _{PLZ} | OE to OUT_X _n | 2.8 | | 6.0 | | 6.2 | | 6.4 | |
| | | 1.6 | | 8.2 | | 8.4 | | 8.6 | |
| t _{OSHL} , | Output-to-Output Skew, Data-to-Output | 3.6 | | 0.15 | | 0.15 | | 0.15 | nS |
| toslh | | 2.8 | | 0.15 | | 0.15 | | 0.15 | |
| | | 1.6 | | 0.15 | | 0.15 | | 0.15 | |

^{1.} Propagation delays defined per Figure 3.

CAPACITANCE

| Symbol | Parameter | Test Conditions | Typ (Note 2) | Unit |
|------------------|-------------------------------|--|--------------|------|
| C _{IN} | Control Pin Input Capacitance | $V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CCA/B}$ | 3.5 | pF |
| C _{I/O} | I/O Pin Input Capacitance | $V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CCA/B}$ | 5.0 | pF |
| C _{PD} | Power Dissipation Capacitance | $V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CCA}, f = 10 \text{ MHz}$ | 10 | pF |

Typical values are at T_A = +25°C.
 C_{PD} is defined as the value of the IC's equivalent capacitance from which the operating current can be calculated from: I_{CC(operating)} ≅ C_{PD} x V_{CC} x f_{IN} x N_{SW} where I_{CC} = I_{CCA} + I_{CCB} and N_{SW} = total number of outputs switching.

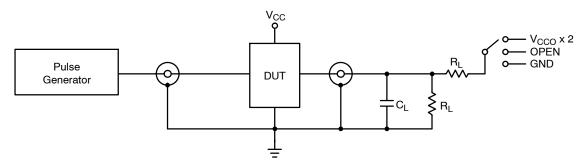


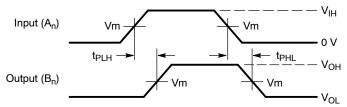
Figure 3. AC (Propagation Delay) Test Circuit

| Test | Switch |
|-------------------------------------|--|
| t _{PLH} , t _{PHL} | OPEN |
| t _{PLZ} , t _{PZL} | V _{CCO} x 2 at VCCB = 3.0 V - 3.6 mV, 2.3 V - 2.7 V, 1.6 V - 1.95 V |
| t _{PHZ} , t _{PZH} | GND |

C_L = 15 pF or equivalent (includes probe and jig capacitance)

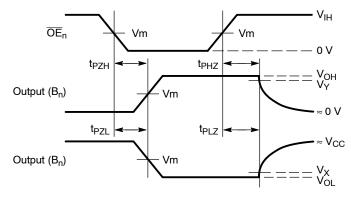
 $R_L = 2 \text{ k}\Omega$ or equivalent

 Z_{OUT} of pulse generator = 50 Ω



Waveform 1 - Propagation Delays

 $t_R = t_F = 2.0 \text{ ns}, 10\% \text{ to } 90\%; f = 1 \text{ MHz}; t_W = 500 \text{ ns}$



Waveform 2 - Output Enable and Disable Times

 t_R = t_F = 2.0 ns, 10% to 90%; f = 1 MHz; t_W = 500 ns

Figure 4. AC (Propagation Delay) Test Circuit Waveforms

| | V _{CC} |
|-----------------|-----------------------|
| Symbol | 3.0 V – 3.6 V |
| V _{mA} | V _{CCA} /2 |
| V _{mB} | V _{CCB} /2 |
| V _X | V _{OL} x 0.1 |
| V _Y | V _{OH} x 0.9 |

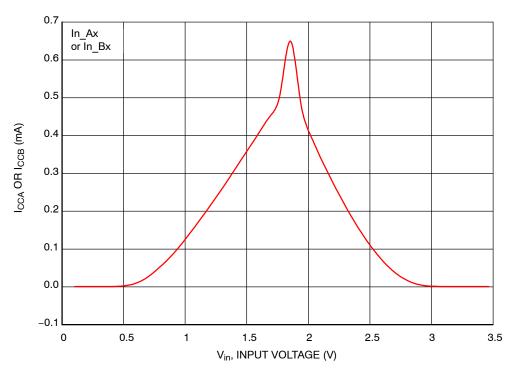
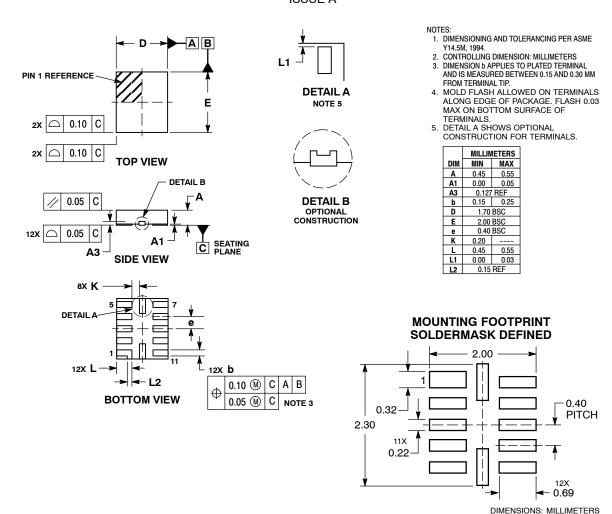


Figure 5. Delta I_{CC} Increase in I_{CC} per Input Voltage, Other Inputs at $V_{CCA}\,/\,V_{CCB}$ or GND

PACKAGE DIMENSIONS

UQFN12 1.7x2.0, 0.4P CASE 523AE-01 ISSUE A



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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